



Product Summary

BV _{DSS}	Rds(on) Max	Q _g Typ	ID Tc = +25°C (Note 7)
40V	2.7mΩ @ V _{GS} = 10V	68.6nC	100A

Description

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

Applications

- Engine management systems
- Body control electronics
- **DC-DC** converters

Site 1:

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and **Robust End Application**
- Low RDS(ON) Minimizes Power Losses
- Low Q_q Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is gualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

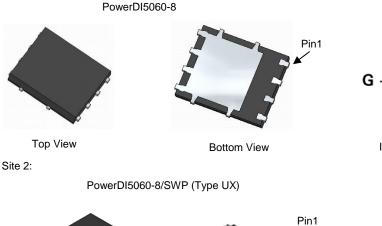
An automotive-compliant part is available under separate datasheet (DMTH4004SPSQ)

Mechanical Data

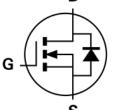
Package: PowerDI[®]5060-8

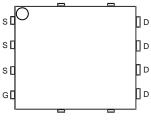
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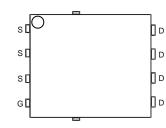
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202. Method 208 @3
- Weight: 0.097 grams (Approximate)











Top View Pin Configuration

Ordering Information (Note 4)

Top View

Notes:

Part Number	Baakaga	Packing		
Part Number	Package	Qty.	Carrier	
DMTH4004SPS-13	PowerDI5060-8	2500	Tape & Reel	
DMTH4004SPS-13	PowerDI5060-8/SWP (Type UX)	2500	Tape & Reel	

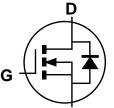
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

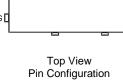
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

S Internal Schematic П



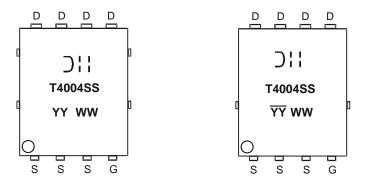
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Internal Schematic





Marking Information



);; = Manufacturer's Marking T4004SS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		VDSS	40	V
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 5)	T _A = +25°C T _A = +70°C	ID	31 26	А
Continuous Drain Current (Note 6)	Tc = +25°C (Note 7)	lD	100	A
	$T_{C} = +100^{\circ}C$		100	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	350	A
Maximum Continuous Body Diode Forward Current (Note 5)		ls	100	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		lsм	350	A
Avalanche Current, L=0.2mH		las	45	A
Avalanche Energy, L=0.2mH		Eas	200	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	3.6	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	41	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	167	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	0.9	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Package limited.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

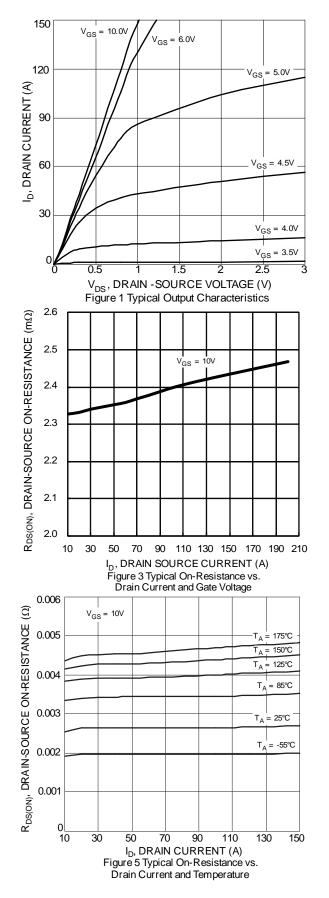
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	CjDCi				•	
Drain-Source Breakdown Voltage	BV _{DSS}	40	—	_	V	$V_{GS} = 0V, I_D = 1mA$
Zero Gate Voltage Drain Current	IDSS	_	—	1	μA	$V_{DS} = 32V, V_{GS} = 0V$
Gate-Source Leakage	Igss	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	VGS(TH)	2	_	4	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	RDS(ON)	—	2.3	2.7	mΩ	$V_{GS} = 10V, I_{D} = 90A$
Diode Forward Voltage	Vsd	—	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		4,305	_	pF	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz
Output Capacitance	Coss	—	1,441	_		
Reverse Transfer Capacitance	Crss	_	102	—		
Gate Resistance	Rg	_	0.77	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg	_	68.6	—		V _{DD} = 20V, I _D = 90A, V _{GS} = 10V
Gate-Source Charge	Qgs	_	16.8	—	nC	
Gate-Drain Charge	Q _{gd}	_	14.2	—		
Turn-On Delay Time	t _{D(ON)}	_	9.5	_		
Turn-On Rise Time	tR	_	6.7	—		$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 20V, \ V_{\text{GS}} = 10V, \\ I_{\text{D}} = 90A, \ R_{\text{G}} = 3.5\Omega \end{array}$
Turn-Off Delay Time	t _{D(OFF)}	_	26.4	_	ns	
Turn-Off Fall Time	tF		8.1	_		
Body Diode Reverse Recovery Time	trr	_	52.4	_	ns	
Body Diode Reverse Recovery Charge	QRR		78.2	—	nC	l⊧ = 50A, di/dt = 100A/µs

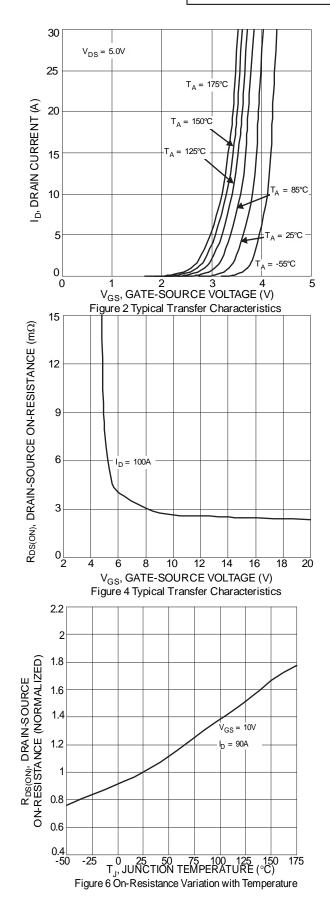
 Notes:
 8. Short duration pulse test used to minimize self-heating effect.

 9. Guaranteed by design. Not subject to production testing.



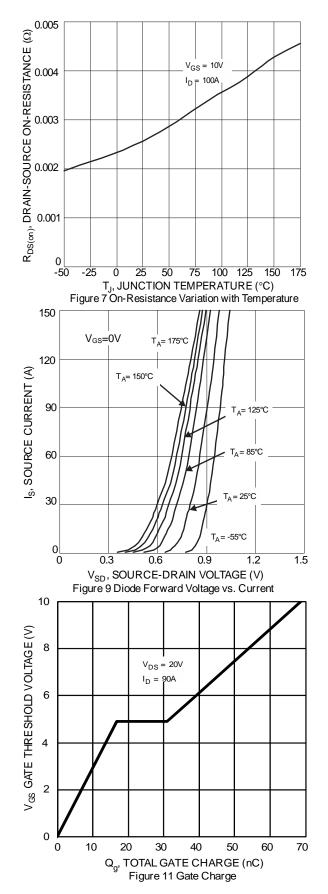
DMTH4004SPS

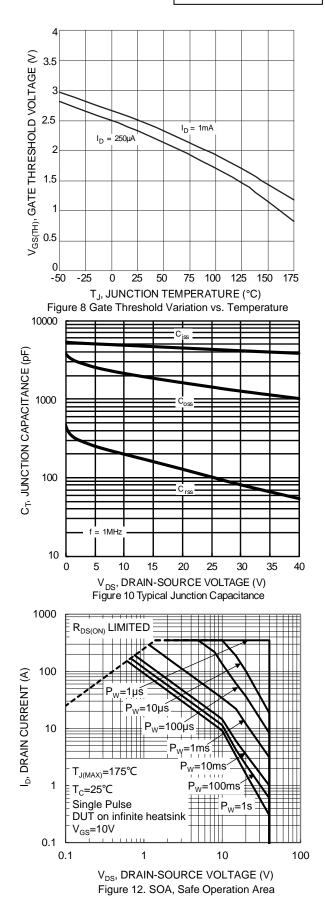




DMTH4004SPS Document number: DS37325 Rev. 6 - 2

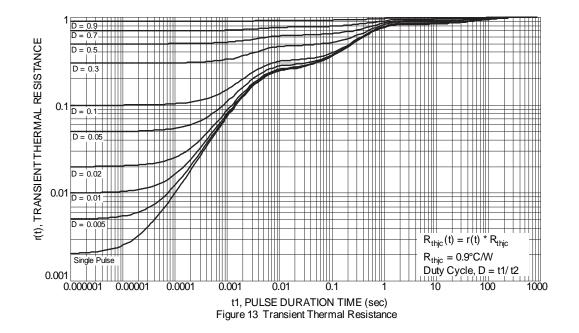






DMTH4004SPS Document number: DS37325 Rev. 6 - 2



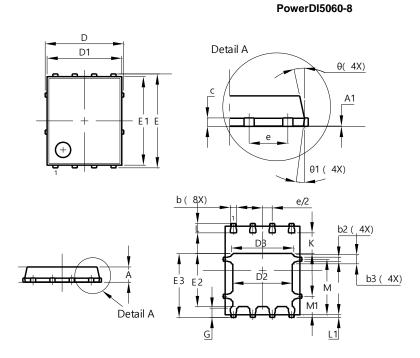




Package Outline Dimensions

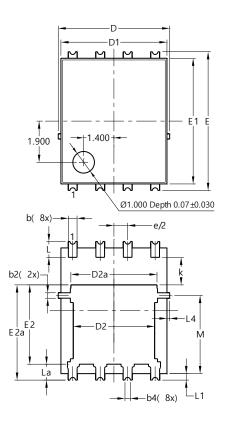
Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

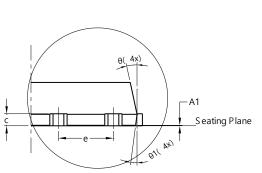


	PowerDI5060-8					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	_			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
E		6.15 BSC	;			
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е		1.27 BSC	;			
G	0.51	0.71	0.61			
K	0.51	-	_			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
01	6°	8°	7°			
Al	All Dimensions in mm					

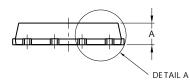
Site 2:



PowerDI5060-8/SWP (Type UX)



DETAIL A



Po	PowerDI5060-8/SWP				
	(Type UX)				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	C).25REF			
С	0.230	0.330	0.277		
D	5	.15 BS0	2		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
E	6	.40 BS0	2		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a		.050RE			
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	Dimensi	ions in	mm		

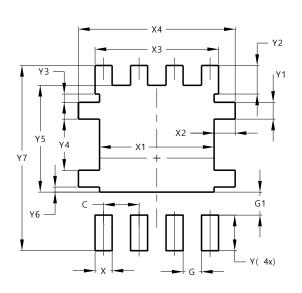
DMTH4004SPS Document number: DS37325 Rev. 6 - 2



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

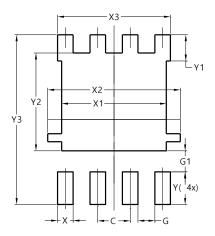


Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	5.190
X3	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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